

SOLID STATE DEVICES, INC.

14005 Stage Road * Santa Fe Springs, Ca 90670 Phone: (562) 404-4474 * Fax: (562) 404-1773

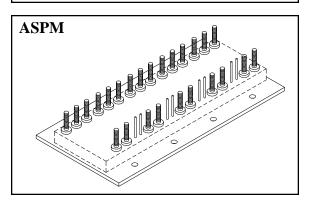
DESIGNER'S DATA SHEET

FEATURES:

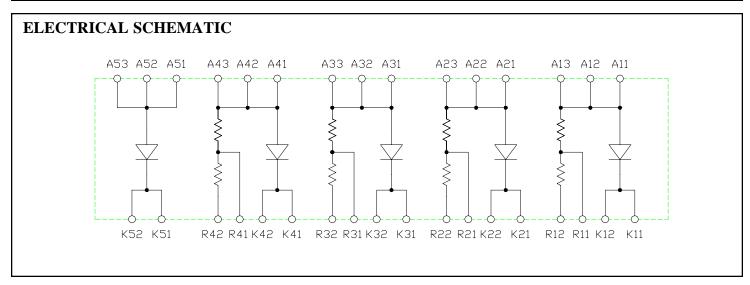
- Application: Power Input Module for Power Controller.
- Fail-Safe Configuration Utilizing Multiple Cell Design.
- Low Mechanical Stress Design.
- Hermetic Sealed Construction for Aerospace Applications.
- Excellent Thermal Management.
- Low Forward Voltage (V_F).
- Voltage Monitor Included for Customer Specified Ratio.
- Full Power Screened Hermetic Discretes.
- TX, TXV, and S-Level Screening Available.
- Consult Factory for Other Configurations and Terminal Styles.

SPMR451-01

180 AMPS/600 VOLTS 5 CELLS SRM POWER MODULE



MAXIMUM RATINGS			
CHARACTERISTIC	SYMBOL	VALUE	UNIT
Peak Repetitive Reverse and DC Blocking Voltage, per Cell	V _{RM} V _{RWM} V _R	600	Volts
Average Rectified Forward Current, per Cell (Non-repetitive, t = 8.3 ms Pulse)	I _O	180	Amps
Peak Surge Current, per Cell (Non-repetitive, t = 8.3 ms Pulse, T _J = 25°C)	I_{FSM}	750	Amps
Operating Temperature Range	T _{OP}	-55 TO +150	°C
Storage Temperature Range	T_{STG}	-55 TO +150	°C
Thermal Resistance, Junction to Base, per Cell	$\Theta_{ m JB}$	0.30	°C/W



PRELIMINARY

SPMR451-01

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ELECTRICAL CHARACTERISTICS @ T _J =25°C, per Cell (Unless Otherwise Specified)					
PARAMETER	SYMBOL	MIN	MAX	UNIT	
$ \begin{array}{ c c c c } \hline \textbf{Instantaneous Forward Voltage} & (I_F = 180A, T_B = 25^{\circ}C) \\ \hline \textbf{Drop} & (I_F = 180A, T_B = -55^{\circ}C) \\ \hline \end{array} $	$egin{array}{c} V_{F1} \ V_{F2} \end{array}$	-	2.5 2.8	Volts	
Reverse Leakage $(V_R = 600V, T_B = 25^{\circ}C)$ $(V_R = 600V, T_B = 100^{\circ}C)$	$I_{R1} I_{R2}$	-	100 1000	μAmps	
Insulation Resistance (All terminals to Base @1000V)	R _{INSUL1}	1	-	GΩ	
Insulation Resistance (Between Cells @1000V)	R _{INSUL2}	1	-	GΩ	
Resistance of Series Resistors	R _{SER}	215	225	kΩ	
Resistance of Monitor Resistors	R _{MON}	4.4	4.6	kΩ	

